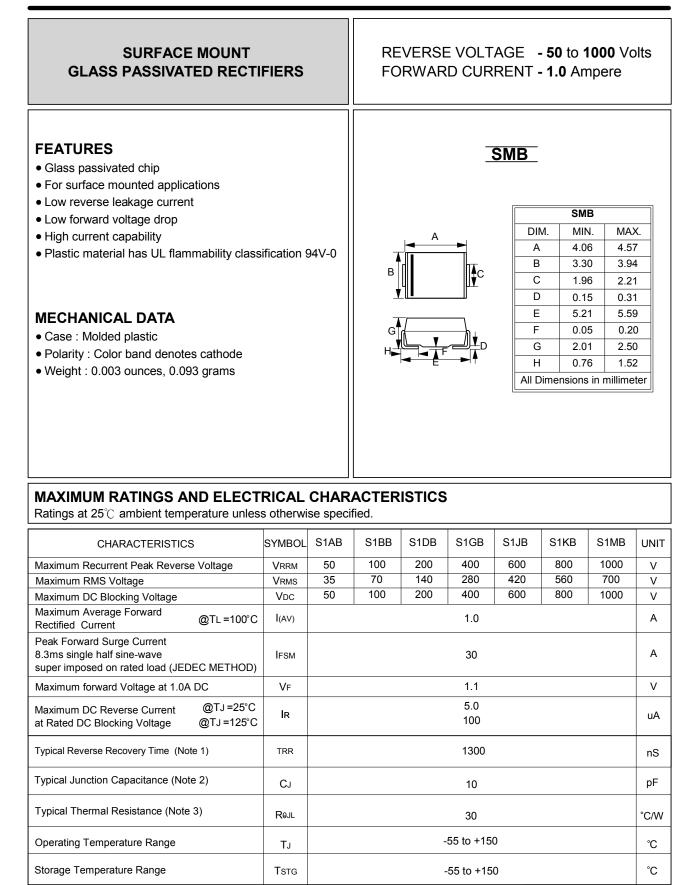
## LITE ON SEMICONDUCTOR

## S1AB thru S1MB

REV. 5, Jun-2014, KSDB01

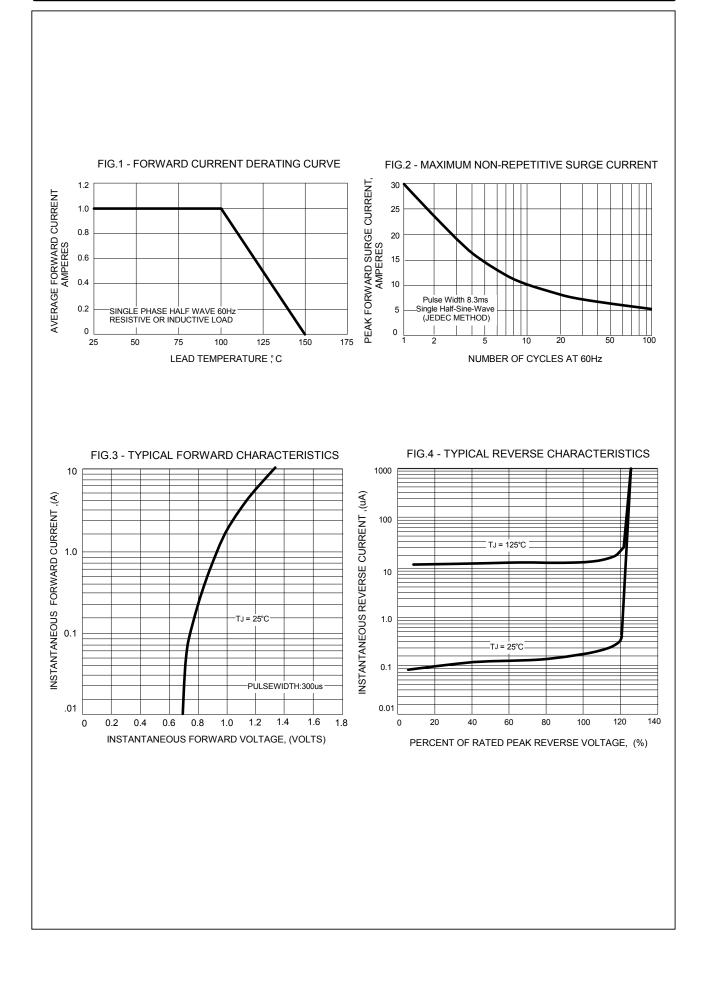


NOTES : 1.Reverse Recovery Test Conditions :IF=0.5A,IR=1.0A,IRR=0.25A.

2.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal Resistance Junction to Lead.

## RATING AND CHARACTERISTIC CURVES S1AB thru S1MB



LITE ON



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